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# Synergistic effects of the zinc acetate additive on the performance enhancement of Sn-based perovskite solar cells†

Tin-based perovskites are promising candidates for preparing lead-free perovskite solar cells due to the optimal bandgap and excellent optoelectronic properties, while the low formation energy of  $\rm Sn^{2+}$  vacancy and facile oxidation of  $\rm Sn^{2+}$  to  $\rm Sn^{4+}$  lead to low efficiency and poor air instability of tin-based PSCs. Here, zinc acetate ( $\rm ZnAc_2$ ) is employed as an additive to form a  $\rm FAl\cdot Snl_2 \cdot ZnAc_2$  intermediate phase in the as-deposited films and control the crystallization process. Besides, the presence of Zn ions could favor the crystal growth by modifying the nucleation process. These synergistic effects lead to high-quality tin-based perovskite films with a large grain size and a low density of  $\rm Sn^{2+}$  vacancies. Moreover,  $\rm ZnAc_2$  could form a complex with  $\rm SnCl_2$  and an antioxidant to uniformly encapsulate the grains and further improve the air stability of the perovskite layers. As a result, the efficiency of tin-based perovskite solar cells is improved from 6.70% to 8.38%. This work demonstrates a viable strategy to fabricate highly efficient and air-stable Sn PSCs by simultaneously suppressing the formation of  $\rm Sn^{2+}$  vacancy and oxidation of  $\rm Sn^{2+}$  in perovskite films.

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### Introduction

Organic–inorganic lead halide perovskite solar cells (PSCs) have achieved a certified power conversion efficiency (PCE) of 25.5%, which rival commercial silicon solar cells.¹ However, the toxic lead contained in state-of-the-art PSCs is a big environmental threat to real-life applications due to its water solubility and easy uptake by plants.²-7 Therefore, eco-friendly lead-free perovskites are desired for future commercialization of perovskite photovoltaic technologies. Recently, various lead-free perovskites have been explored, such as tin (Sn), 8-12 germanium (Ge), 13,14 bismuth (Bi), 15,16 and antimony (Sb). 17,18 Among them, tin-based perovskites have a similar crystal structure to lead counterparts, an optimal bandgap (1.2–1.4 eV) close to the Shockley–Queisser limit, high carrier mobility and low exciton energy, which enable great potential for high efficiency lead-free PSCs. 19–23 However, the PCE of tin-based PSCs is much lower than that of lead-based analogs. 24

The relatively lower efficiency of tin-based PSCs compared with lead counterparts is ascribed to the intrinsic chemical

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instability of  $\mathrm{Sn}^{2+}$  and difficulty in controlling the morphology of perovskite films due to the fast crystallization. The low formation energy of  $\mathrm{Sn}^{2+}$  vacancy in the crystallization process and the easy oxidation of  $\mathrm{Sn}^{2+}$  to  $\mathrm{Sn}^{4+}$  upon air exposure lead to the higher carrier recombination and metallic behavior of tin-based perovskite films due to high hole density. The fast crystallization due to the strong Lewis acidity of  $\mathrm{Sn}^{2+}$  results in poor-quality perovskite films with pin holes and randomly oriented crystals. Hence, some strategies are explored to increase the formation energy of  $\mathrm{Sn}^{2+}$  vacancy and prevent the oxidation of  $\mathrm{Sn}^{2+}$  via composition engineering and additive introduction. Capacitate in the control of  $\mathrm{Sn}^{2+}$  via composition engineering and additive introduction.

Recently, our group reported techniques for the *in situ* encapsulation of tin-based perovskite grains by introducing antioxidants (hydroxybenzene sulfonic acid and gallic acid), which could effectively prolong the air lifetime of tin-based PSCs. <sup>39,41</sup> Although the oxidation of Sn<sup>2+</sup> by outer oxygen is highly suppressed, the intrinsic Sn<sup>2+</sup> vacancy in perovskite films, especially at grain boundaries, is not effectively alleviated due to the decreased grain size by the introduction of antioxidant additives, which limits further efficiency improvement. Therefore, a new strategy is needed to control the crystallization process to further decrease Sn<sup>2+</sup> vacancies to improve the efficiency of our tin-based PSCs.

Herein, a small amount of zinc acetate (ZnAc<sub>2</sub>) is introduced into our perovskite precursors to control the crystallization

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process during film deposition. It is found that the grain size of perovskite films is enlarged and defect density is efficiently suppressed, which can be ascribed to the following two effects. First, a FAI·SnI<sub>2</sub>·ZnAc<sub>2</sub> intermediate phase is formed during the crystallization process due to the strong bonding of the Lewis base group of Ac<sup>-</sup> and the Lewis acid of Sn<sup>2+</sup>. This intermediate phase could avoid the loss of Sn<sup>2+</sup> during the crystallization process and also retard the crystallization process. Second, Zn ions can modify the nucleation and crystal growth processes. These synergistic effects increase the grain size and improve the quality of FASnI<sub>3</sub> perovskite films. After the crystallization process, ZnAc2 could uniformly encapsulate perovskite grains by forming a complex with SnCl<sub>2</sub> and an antioxidant (KHQSA) owing to the interaction between the Ac group and Sn<sup>2+</sup>. This further enhances the air stability of the FASnI<sub>3</sub> perovskite layer. Thanks to the enlarged grain size and lowered defect density in perovskite films, the efficiency of FASnI<sub>3</sub> PSCs is improved from 6.70% to 8.38%.

Research Article

The perovskite films were fabricated *via* one-step spin-coating of the perovskite precursor with different amounts of ZnAc<sub>2</sub>. The reference perovskite precursor is composed of FAPbI3 in a solvent mixture of DMF/DMSO with excess 7.0 mol% SnCl<sub>2</sub> and 1.5 mol% KHQSA, as reported in our previous work.39 Fig. 1 shows the SEM images of perovskite films with the

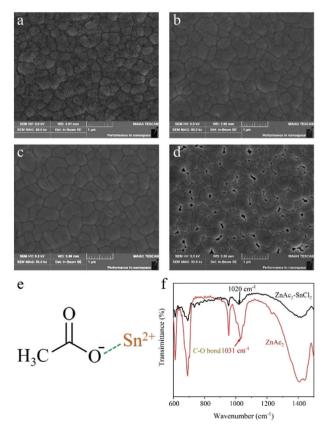


Fig. 1 SEM images of perovskite films without (a) and with 0.5 mol% (b), 1.0 mol% (c) and 3.0 mol% (d) ZnAc2 addition. (e) The illustration of the interaction between the Ac<sup>-</sup> group and Sn<sup>2+</sup>. (f) FTIR patterns of ZnAc<sub>2</sub> and ZnAc2-SnCl2 complex powders

addition of different amounts of ZnAc2. It can be observed that the grain size is gradually enlarged when increasing the amount of ZnAc<sub>2</sub> to 1.0 mol%. By further increasing the amount of ZnAc<sub>2</sub> to 3.0 mol%, the grain size is decreased and several holes appear in the films. In addition, no aggregates are formed in all films, suggesting that ZnAc<sub>2</sub> is uniformly dispersed in the films. Therefore, through the addition of a suitable amount of ZnAc2, the grain size could be successfully enlarged and the morphology of FASnI<sub>3</sub> perovskite films could be optimized.

It should be noted that a Lewis adduct could be formed between a Lewis base Ac<sup>-</sup> and a Lewis acid Sn<sup>2+</sup>, as shown in Fig. 1e. Fourier transform infrared (FTIR) spectroscopy characterization was employed to verify this interaction. Fig. 1f shows the FTIR patterns of ZnAc2 and SnCl2-ZnAc2 composite powders, respectively. The C-O stretching vibration for pure ZnAc<sub>2</sub> is observed at 1031 cm<sup>-1</sup>, while for ZnAc<sub>2</sub>-SnCl<sub>2</sub> the C-O stretching vibration is shifted to a lower wavenumber of 1020 cm<sup>-1</sup>. This result confirms the interaction between the Ac<sup>-</sup> group and Sn<sup>2+</sup>. Hence, in the crystallization process, the formation of the FAI·SnI<sub>2</sub>·ZnAc<sub>2</sub> intermediate phase could be due to the interaction between the Ac<sup>-</sup> group and Sn<sup>2+</sup>. <sup>43</sup> This intermediate phase could retard the crystallization process to enlarge the grain size.<sup>26</sup> Moreover, the introduction of Zn ions could affect the nucleation and subsequent crystal growth process, which also increased the grain size, 44,45 which is similar to the effect observed in lead-based perovskites with the introduction of Zn ions.46 The deceased grain size and occurrence of holes with excessive ZnAc2 addition could be ascribed to the steric effect of ZnAc2, which separates the adjacent perovskite grains.43

X-ray diffraction (XRD) characterization was conducted on these films to study the effect of ZnAc2 on the crystallinity of FAPbI<sub>3</sub> (see the ESI,† Fig. S1). The perovskite film with the addition of 1.0 mol% ZnAc2 shows the highest intensity, indicating the high quality due to the large grains and better crystallinity. No peak shift is observed in all films, suggesting that Zn and Ac ions are not incorporated into the FASnI<sub>3</sub> lattice. This is because the molar ratio of FAI and SnI2 is equal in the precursor and the Lewis acidity of Sn<sup>2+</sup> is much stronger than that of  $Zn^{2+}$ . Zn ions are unable to substitute  $Sn^{2+}$  in FASnI<sub>3</sub> under this condition. Therefore, it is reasonable to assume that ZnAc2 is uniformly dispersed at grain boundaries and surfaces in the crystallized perovskite films by forming a complex with SnCl<sub>2</sub> and the antioxidant (KHQSA). The pure SnCl<sub>2</sub> and SnCl<sub>2</sub>-ZnAc<sub>2</sub> composite films were prepared and optical microscopic characterization was conducted to confirm this assumption (see the ESI,† Fig. S2). The pure SnCl<sub>2</sub> film is very rough due to the formation of branched crystals, while a uniform and smooth morphology is formed for the SnCl<sub>2</sub>-ZnAc<sub>2</sub> composite film where the crystallization of SnCl<sub>2</sub> is significantly suppressed. Therefore, based on FTIR and optical microscopy characterization, it can be concluded that ZnAc<sub>2</sub> formed a complex with SnCl<sub>2</sub> and the antioxidant to encapsulate the perovskite grains in the crystalized films, which can further enhance the protection of Sn perovskites from oxidation.

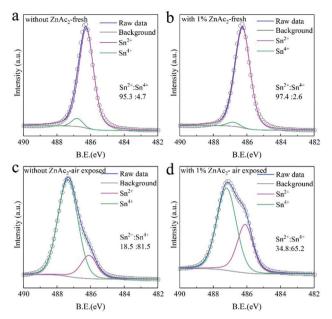


Fig. 2 XPS Sn 3d<sup>5/2</sup> spectra of FASnI<sub>3</sub> films without (a and c) and with (b and d) 1.0 mol% ZnAc<sub>2</sub>. All films were prepared with SnCl<sub>2</sub> and KHQSA as the basic conditions. Samples (a and b) were characterized under fresh conditions; Samples (c and d) were characterized after exposure to air for 12 h (RH20%).

X-ray photoelectron spectroscopy (XPS) characterization was performed to investigate the Sn<sup>4+</sup> content in FASnI<sub>3</sub> films with and without the addition of 1% ZnAc2. As shown in Fig. 2a and b, the Sn<sup>4+</sup> content in fresh FASnI<sub>3</sub> is 4.7%, while it is decreased to 2.6% in fresh FASnI3 with the introduction of 1.0 mol% ZnAc<sub>2</sub>. This suggests that the formed intermediate phase could suppress the oxidation of Sn<sup>2+</sup> in the crystallization process. Moreover, the slower color change of the precursor solution with increasing amount of ZnAc2 further demonstrates that the presence of ZnAc2 could enhance the stability of Sn2+ in the precursor (see the ESI,† Fig. S3).<sup>47</sup> For the Sn perovskite films exposed to air for 12 h, the Sn<sup>4+</sup> content is 65.2% for the ZnAc<sub>2</sub> doped film, which is lower than the value (81.5%) for the pristine film. The better air stability is attributed to the much thicker encapsulation complex layer with the addition of ZnAc<sub>2</sub>.

Fig. 3a shows the steady-state photoluminescence spectra of perovskite films with the addition of different amounts of

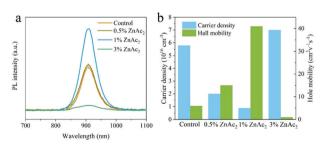


Fig. 3 (a) Steady-state photoluminescence spectra of Sn perovskite thin films deposited on glass substrates with the addition of different amounts of ZnAc<sub>2</sub>. (b) Carrier density and carrier mobility of Sn perovskite films with the addition of different amounts of ZnAc2 estimated from Hall effect measurements

ZnAc<sub>2</sub>. It can be observed that the perovskite film with the addition of 1.0 mol% ZnAc2 demonstrates the highest PL intensity, suggesting the lowest defect density, which results from the efficient suppression of Sn<sup>2+</sup> vacancy. Further incorporation would lead to a lower PL intensity due to the formation of pinholes in the films shown by the SEM image in Fig. 1d. The carrier transport property of perovskite films was investigated by Hall effect measurements using the four-contact Hall bar method.<sup>25</sup> Fig. 3b shows the hole carrier density and mobility of FASnI<sub>3</sub> films with the addition of different amounts of ZnAc<sub>2</sub>. The 1.0 mol% ZnAc2 doped film exhibits a much lower hole carrier density and a higher hole mobility than the reference one. Therefore, the addition of ZnAc<sub>2</sub> could significantly improve the optoelectronic and charge transport properties of Sn perovskite films by efficiently suppressing the formation of Sn<sup>2+</sup> vacancy and enhancing the film crystallinity.

The PSCs with the p-i-n structure of ITO/NiO<sub>x</sub>/FASnI<sub>3</sub>/PCBM/ BCP/Ag, as shown in Fig. 4a, were fabricated to demonstrate the effect of ZnAc<sub>2</sub> on the photovoltaic performance of devices. 7.0 mol% SnCl<sub>2</sub> and 1.5 mol% KHQSA were added into the precursor as basic additives. Fig. 4b shows the photovoltaic performances of PSCs with the addition of different amounts of ZnAc2. It can be observed that, by increasing the amount of ZnAc<sub>2</sub> to 1.0 mol%, the PCE could be improved gradually with overall enhancement in the parameters. This improvement should be attributed to the enlarged grain size and suppressed defect density (mainly Sn<sup>+2</sup> vacancy). Excessive ZnAc<sub>2</sub> addition (3.0 mol%) leads to inferior performance due to the presence of pin-holes in the films. The champion device with 1.0 mol% ZnAc<sub>2</sub> could reach a PCE of 8.38% with a  $V_{\rm oc}$  of 0.54 V, a  $J_{\rm sc}$  of  $22.49 \text{ mA cm}^{-2}$  and an FF of 0.69. Negligible hysteresis is observed (see the ESI,† Fig. S4). In comparison, the control device demonstrates a PCE of 6.70% with a  $V_{\rm oc}$  of 0.50 V, a  $J_{\rm sc}$  of

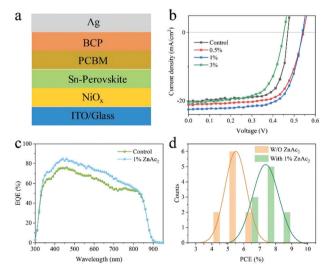


Fig. 4 (a) Schematic illustration of the device structure. (b) J-V cures of PSCs with the addition of different amounts of ZnAc2. (c) EQE spectra of champion PSCs without and with 1.0 mol% ZnAc2 addition, respectively. (d) The statistics of PCE distribution of 10 PSCs without and with 1.0 mol% ZnAc2, respectively.

20.21 mA cm<sup>-2</sup> and an FF of 0.67. The corresponding external quantum efficiency (EQE) spectra are presented in Fig. 4c. The calculated  $J_{\rm sc}$  values are 19.24 mA cm<sup>-2</sup> and 21.59 mA cm<sup>-2</sup> for control and doped devices, respectively, which are close to the J-V measured values. The higher current density is attributed to the larger grain size and lower defect density with the introduction of ZnAc<sub>2</sub>. Fig. 4d shows the statistics of PCEs of 10 devices with and without the addition of 1.0 mol% ZnAc2. The average PCE for control devices is  $5.5 \pm 0.3\%$ . Upon ZnAc<sub>2</sub> addition, the average PCE is increased to 7.25  $\pm$  0.5%. This statistic verifies the positive effect of ZnAc<sub>2</sub> on the performance enhancement of Sn PSCs.

## Conclusions

In summary, ZnAc2 has been successfully employed to enlarge the grain size and decrease the defect density of FASnI<sub>3</sub> films. The improvement can be ascribed to the following reasons. First, the interaction between the Ac<sup>-</sup> group and Sn<sup>2+</sup> enables the formation of a FAI·SnI<sub>2</sub>·ZnAc<sub>2</sub> intermediate phase, leading to an enlarged grain size and suppressed Sn<sup>2+</sup> vacancy of FASnI<sub>3</sub> films. Besides, Zn ions could modify the nucleation to favor the crystal growth. Finally, ZnAc2 could form a complex with SnCl2 and the antioxidant to uniformly encapsulate the perovskite grains, which further strengthens the protection of perovskite films from oxidation. Consequently, the average efficiency of air-stable Sn PSCs has been improved from 5.5% to 7.25% with a relative enhancement of 31%. The efficiency of champion devices is improved from 6.70% to 8.38% with the addition of ZnAc<sub>2</sub>. Our strategy provides a facile and compatible route to prepare air-stable Sn perovskite films with high quality, which can be expected to be applied in other optoelectronic devices.

# **Experimental**

#### Materials

Formamidinium iodide (CH(NH<sub>2</sub>)<sub>2</sub>I) was purchased from GreatCell Solar; SnI<sub>2</sub> (99.999%), zinc acetate, nickel(II) nitrate hexahydrate (Ni(NO<sub>3</sub>)<sub>2</sub>·6H<sub>2</sub>O, 98%) and DMF (anhydrous, 99.8%) were purchased from Alfa Aesar. Bathocuproine (BCP, 96%), chlorobenzene (anhydrous, 99.8%), and DMSO (anhydrous, 99.9%) were purchased from Sigma-Aldrich. Phenyl-C71-butyric acid methyl ester (PC<sub>71</sub>BM) was purchased from Nano-C Ltd.

#### Preparation of SnCl<sub>2</sub> and SnCl<sub>2</sub>-ZnAc<sub>2</sub> powders

SnCl2 was dissolved in DMSO with a 1 M molar weight. The SnCl2-ZnAc2 complex was prepared by dissolving SnCl2 and ZnAc<sub>2</sub> in DMSO with 1 M and 0.5 M molar weights, respectively. Then the SnCl<sub>2</sub> and SnCl<sub>2</sub>-ZnAc<sub>2</sub> solutions were spin-coated onto glass substrates, respectively, followed by thermal annealing at 100 °C to facilitate crystallization for 10 hours. Then the powders could be obtained by scraping the films from the substrates.

#### **Device fabrication**

ITO/glass substrates were sequentially washed with distilled water, acetone and isopropyl alcohol. Then, NiOx films were prepared by spin-coating NiO<sub>r</sub> solution by dispersing NiO<sub>r</sub> nanocrystals in water as reported in our previous work.<sup>39,41</sup> The perovskite films were prepared by spin-coating the 0.8 M FASnI<sub>3</sub> precursor containing FAI, SnI<sub>2</sub>, SnCl<sub>2</sub>, KHQSA, and  $ZnAc_2$  at a molar ratio of 1:1:0.07:0.015:x (x = 0, 0.005, 0.01, or 0.03) mixed in DMF/DMSO (13:1, v/v) at 5000 rpm for 30 s. During the spin-coating process, 90 μL of chlorobenzene was dripped on a rotating substrate at 10 s after starting. All perovskite films were annealed at 70 °C for 10 min. Next, electron transport layers (ETLs) were prepared by spin-coating a solution of PCBM in chlorobenzene (20 mg mL<sup>-1</sup>) at 1500 rpm for 40 s. Bathocuproine (BCP, Sigma, 96%) dissolved in IPA  $(0.5 \text{ mg mL}^{-1})$  was spin-coated on the PCBM films at 4500 rpm for 30 s. Finally, devices were obtained with the evaporation of silver (Ag) top electrodes through a shadow mask. The area of the PSC is designed to be 4.8 mm<sup>2</sup>.

#### **Device characterization**

Scanning electron microscopy (SEM) characterization was performed on a JEOL JSM 6335F SEM. X-ray diffraction measurements were performed using a Rigaku SmartLab X-ray diffractometer operating at room temperature. Time-resolved photoluminescence measurements of the samples were carried out by using an Edinburgh FLSP920 fluorescence spectrophotometer. A 485 nm laser was used as the excitation light source. Hall effect measurements were conducted using a four-probe Ecopia Hall Effect Measurement System (HMS-5000). FTIR spectroscopy was performed on a Bruker Vertex-70 in the attenuated total reflection mode. The current density versus voltage (J-V) characteristics of the PSCs were measured by using a Keithley 2400 source meter under the illumination of an AM 1.5 solar simulator with a light intensity of 100 mW cm<sup>-2</sup> (Newport 91160, 300 W). The light intensity was calibrated with a standard silicon solar cell. The external quantum efficiencies of the PSCs were measured with a standard test system, including a xenon lamp (Oriel 66,02, 300 W), a Si detector (Oriel 76175\_71580), a monochromator (Newport 66902) and a dual-channel power meter (Newport 2931 C).

## Conflicts of interest

There are no conflicts to declare.

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